

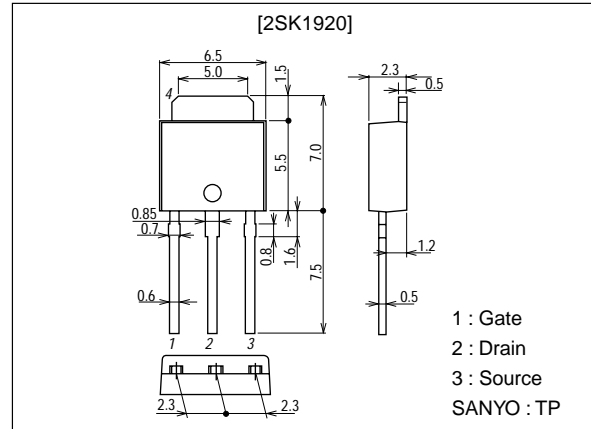
**2SK1920****Ultrahigh-Speed Switching Applications****Features**

- Low ON resistance.
- Ultrahigh-speed switching.
- Low-voltage drive.

Package Dimensions

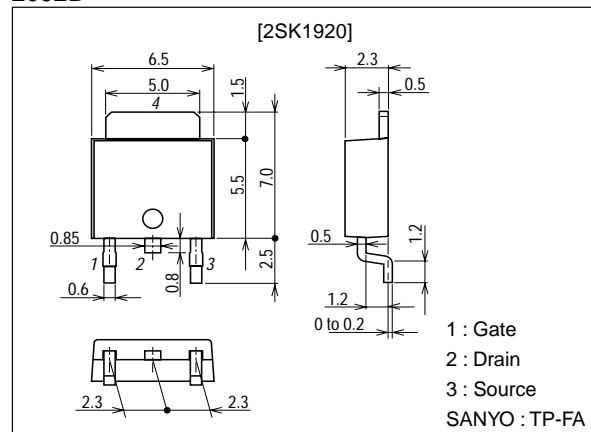
unit:mm

2083B



unit:mm

2092B



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Specifications

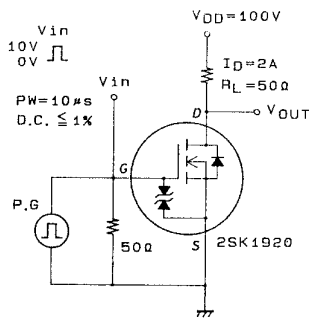
Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		250	V
Gate-to-Source Voltage	V_{GSS}		± 30	V
Drain Current (DC)	I_D		4	A
Drain Current (pulse)	I_{DP}	$PW \leq 10\mu\text{s}$, duty cycle $\leq 1\%$	16	A
Allowable Power Dissipation	P_D		1.0	W
		$T_c = 25^\circ\text{C}$	30	W
Channel Temperature	T_{ch}		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

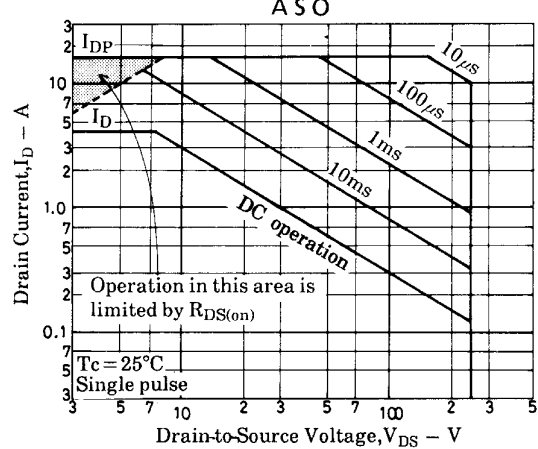
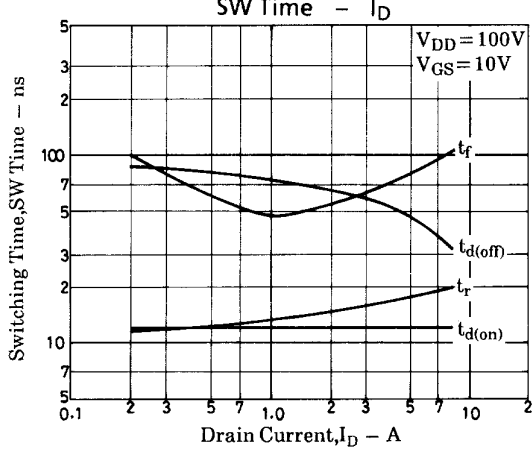
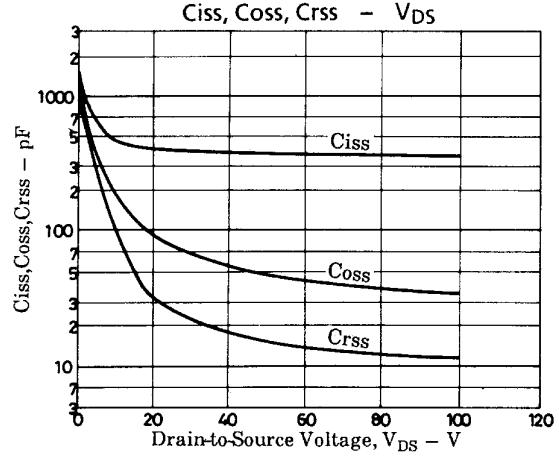
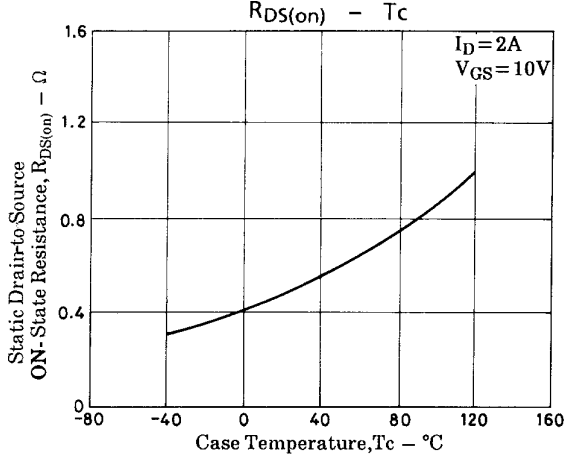
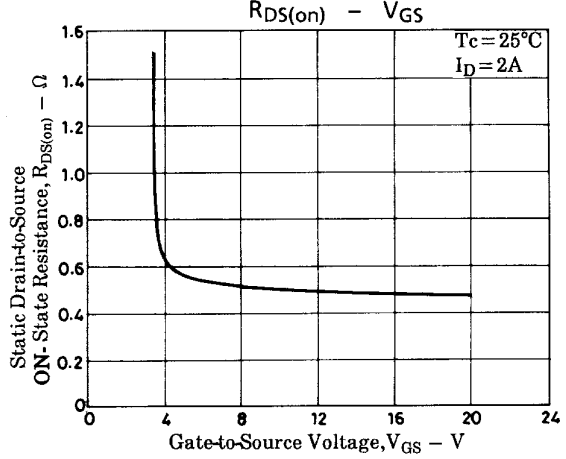
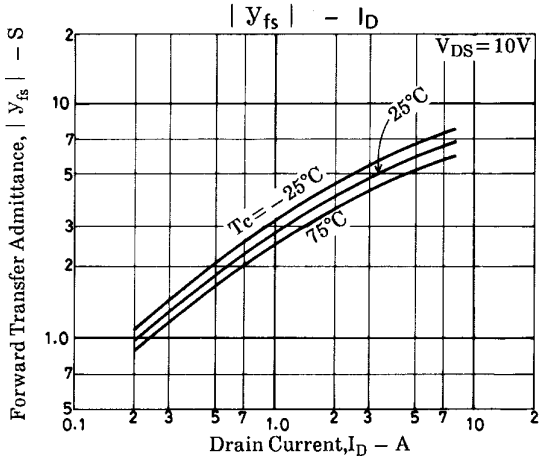
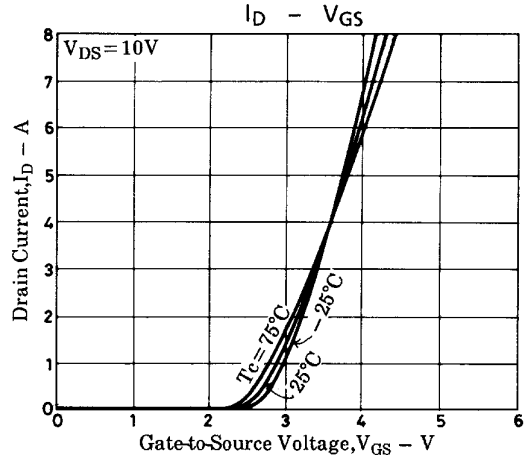
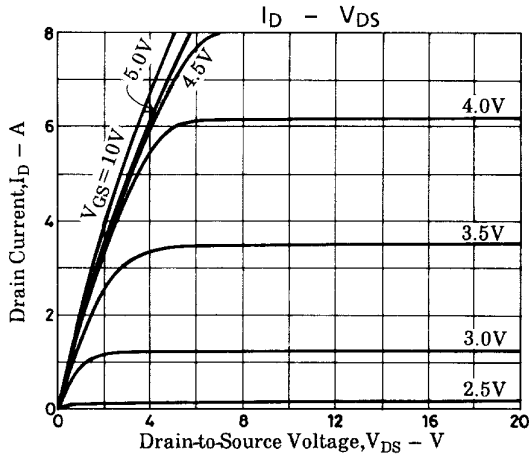
Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 1\text{mA}$, $V_{GS} = 0$	250			V
Gate-to-Source Breakdown Voltage	$V_{(BR)GSS}$	$I_G = \pm 100\mu\text{A}$, $V_{DS} = 0$	± 30			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 250\text{V}$, $V_{GS} = 0$			100	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 25\text{V}$, $V_{DS} = 0$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = 10\text{V}$, $I_D = 1\text{mA}$	1.5		2.5	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = 10\text{V}$, $I_D = 2\text{A}$	2.5	4		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)}$	$I_D = 2\text{A}$, $V_{GS} = 10\text{V}$		500	700	$\text{m}\Omega$
Input Capacitance	C_{iss}	$V_{DS} = 20\text{V}$, $f = 1\text{MHz}$		420		pF
Output Capacitance	C_{oss}	$V_{DS} = 20\text{V}$, $f = 1\text{MHz}$		95		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS} = 20\text{V}$, $f = 1\text{MHz}$		30		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit		12		ns
Rise Time	t_r	See specified Test Circuit		15		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit		65		ns
Fall Time	t_f	See specified Test Circuit		55		ns
Diode Forward Voltage	V_{SD}	$I_S = 4\text{A}$, $V_{GS} = 0$		1.0	1.5	V

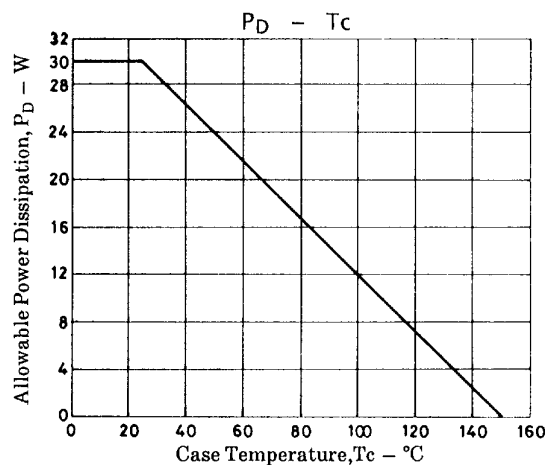
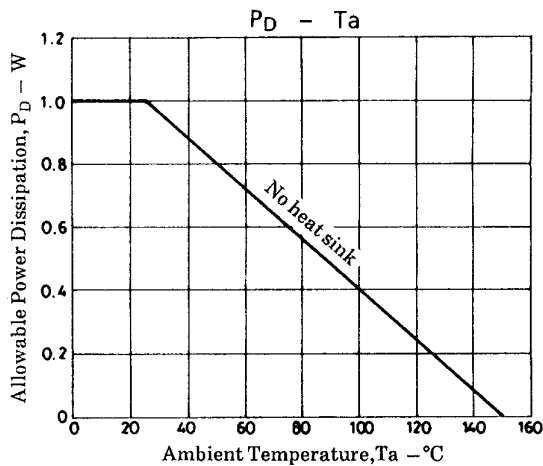
Switching Time Test Circuit



2SK1920



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